



Bipolar PNP Bare Die – BTP6908

Part Description

The BTP6908 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = -32V
- VCEO = -20V
- VEBO = -5V
- hFE = 85-375 @ VCE = -1V, IC = -0.5A
- VCE(Sat) = -0.5V @ IC = -1A, IB = -100mA
- fT = 40 MHz @ VCE = -5V, IE = 0A
- COBO = 18pF @ VCB = -10V

Features

Low VCE(sat). Designed to provide performance equivalent to BCP69

Die Size (Unawn)

670µm X 670µm, 26 Mils X 26 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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